

LMH6609 900MHz Voltage Feedback Op Amp

Check for Samples: [LMH6609](#)

FEATURES

- 900MHz –3dB bandwidth ($A_V = 1$)
- Large signal bandwidth and slew rate 100% tested
- 280MHz –3dB bandwidth ($A_V = +2$, $V_{OUT} = 2V_{PP}$)
- 90mA linear output current
- 1400V/ μ s slew rate
- Unity gain stable
- <1mV input Offset voltage
- 7mA Supply current (no load)
- 6.6V to 12V supply voltage range
- 0.01%/0.026° differential gain/phase PAL
- 3.1nV/ $\sqrt{\text{Hz}}$ voltage noise
- Improved replacement for CLC440, CL420, CL426

APPLICATIONS

- Test equipment
- IF/RF amplifier
- A/D Input driver
- Active filter
- Integrator
- DAC output buffer
- TI's Transimpedance amplifier

DESCRIPTION

The LMH6609 is an ultra wideband, unity gain stable, low power, voltage feedback op amp that offers 900MHz bandwidth at a gain of 1, 1400V/ μ s slew rate and 90mA of linear output current.

The LMH6609 is designed with voltage feedback architecture for maximum flexibility especially for active filters and integrators. The LMH6609 has balanced, symmetrical inputs with well-matched bias currents and minimal offset voltage.

With Differential Gain of 0.01% and Differential Phase of 0.026° the LMH6609 is suited for video applications. The 90mA of linear output current makes the LMH6609 suitable for multiple video loads and cable driving applications as well.

The supply voltage is specified at 6.6V and 10V. A low supply current of 7mA (at 10V supply) makes the LMH6609 useful in a wide variety of platforms, including portable or remote equipment that must run from battery power.

The LMH6609 is available in the industry standard 8-pin SOIC package and in the space-saving 5-pin SOT-23 package. The LMH6609 is specified for operation over the -40°C to +85°C temperature range. The LMH6609 is manufactured in state-of-the-art VIP10™ technology for high performance.

Typical Application

$$K = 1 + \frac{R_F}{R_G} \quad Q = \frac{m}{1 + m^2(2 - K)} \quad \omega_0 = \frac{1}{mRC}$$

Q, K ARE UNITLESS.
 ω_0 IS RELATED TO BANDWIDTH AND IS IN UNITS OF RADIANS/SEC. DIVIDE ω_0 BY 2π TO GET IT IN Hz.
 REFER TO OA-26 FOR MORE INFORMATION.

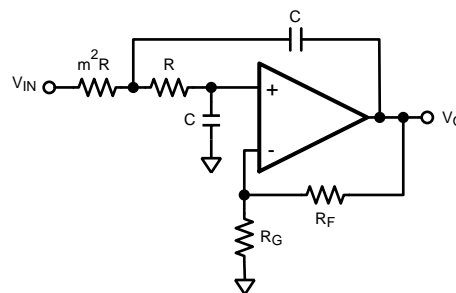


Figure 1. Sallen Key Low Pass Filter with Equal C Value



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

VIP10 is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2003–2013, Texas Instruments Incorporated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾

V_S ($V^+ - V^-$)	$\pm 6.6V$
I_{OUT}	⁽²⁾
Common Mode Input Voltage	V^+ to V^-
Maximum Junction Temperature	$+150^\circ C$
Storage Temperature Range	$-65^\circ C$ to $+150^\circ C$
Lead Temperature Range	$+300^\circ C$
ESD Tolerance ⁽³⁾	
Human Body Model	2000V
Machine Model	200V

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. For specifications, see the Electrical Characteristics tables.
- (2) The maximum output current (I_{OUT}) is determined by device power dissipation limitations. See the Power Dissipation section of the Application Section for more details.
- (3) Human body model, 1.5k Ω in series with 100pF. Machine model, 0 Ω in series with 200pF.

Operating Ratings ⁽¹⁾

Thermal Resistance	Package	(θ_{JC})	(θ_{JA})
	8-Pin SOIC	$65^\circ C/W$	$145^\circ C/W$
	5-Pin SOT23	$120^\circ C/W$	$187^\circ C/W$
Operating Temperature		$-40^\circ C$	$+85^\circ C$
Nominal Supply Voltage ⁽²⁾		$\pm 3.3V$	$\pm 6V$

- (1) The maximum output current (I_{OUT}) is determined by device power dissipation limitations. See the Power Dissipation section of the Application Section for more details.
- (2) Nominal Supply voltage range is for supplies with regulation of 10% or better.

$\pm 5V$ Electrical Characteristics

Unless specified, $A_V = +2$, $R_F = 250\Omega$; $V_S = \pm 5V$, $R_L = 100\Omega$; unless otherwise specified. **Boldface** limits apply over temperature Range. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Frequency Domain Response						
SSBW	-3dB Bandwidth	$V_{OUT} = 0.5V_{PP}$		260		MHz
LSBW	-3dB Bandwidth	$V_{OUT} = 4.0V_{PP}$	150	170		MHz
SSBWG1	-3dB Bandwidth $A_V = 1$	$V_{OUT} = 0.25V_{PP}$		900		MHz
GFP	.1dB Bandwidth	Gain is Flat to .1dB		130		MHz
DG	Differential Gain	$R_L = 150\Omega$, 4.43MHz		0.01		%
DP	Differential Phase	$R_L = 150\Omega$, 4.43MHz		0.026		deg
Time Domain Response						
TRS	Rise and Fall Time	1V Step		1.6		ns
TRL		4V Step		2.6		ns
t_s	Settling Time to 0.05%	2V Step		15		ns
SR	Slew Rate	4V Step ⁽²⁾	1200	1400		V/ μs

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where $T_J > T_A$. See Applications Section for information on temperature derating of this device. Min/Max ratings are based on product characterization and simulation. Individual parameters are tested as noted.
- (2) Slew rate is Average of Rising and Falling 40-60% slew rates.

±5V Electrical Characteristics (continued)

Unless specified, $A_V = +2$, $R_F = 250\Omega$; $V_S = \pm 5V$, $R_L = 100\Omega$; unless otherwise specified. **Boldface** limits apply over temperature Range. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Distortion and Noise Response						
HD2	2 nd Harmonic Distortion	$2V_{PP}$, 20MHz		–63		dBc
HD3	3 rd Harmonic Distortion	$2V_{PP}$, 20MHz		–57		dBc
	Equivalent Input Noise					
VN	Voltage Noise	>1MHz		3.1		nV/ \sqrt{Hz}
CN	Current Noise	>1MHz		1.6		pA/ \sqrt{Hz}
Static, DC Performance						
V_{IO}	Input Offset Voltage			±0.8	±2.5 ±3.5	mV
	Input Voltage Temperature Drift			4		$\mu V/^\circ C$
I_{BN}	Input Bias Current			–2	±5 ±8	μA
	Bias Current Temperature Drift			11		nA/ $^\circ C$
I_{BI}	Input Offset Current			0.1	±1.5 ±3	μA
PSRR	Power Supply Rejection Ratio	DC, 1V Step	67 65	73		dB
CMRR	Common Mode Rejection Ratio	DC, 2V Step	67 65	73		dB
I_{CC}	Supply Current	$R_L = \infty$		7.0	7.8 8.5	mA
Miscellaneous Performance						
R_{IN}	Input Resistance			1		M Ω
C_{IN}	Input Capacitance			1.2		pF
R_{OUT}	Output Resistance	Closed Loop		0.3		Ω
V_O	Output Voltage Range	$R_L = \infty$	±3.6 ±3.3	±3.9		V
V_{OL}		$R_L = 100\Omega$	±3.2 ±3.0	±3.5		V
CMIR	Input Voltage Range	Common Mode, CMRR > 60dB	±2.8 ±2.5	±3.0		V
I_O	Linear Output Current	V_{OUT}	±60 ±50	±90		mA

±3.3V Electrical Characteristics

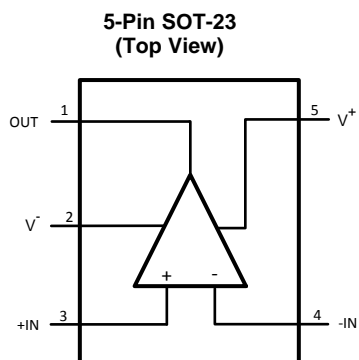
Unless specified, $A_V = +2$, $R_F = 250\Omega$; $V_S = \pm 3.3V$, $R_L = 100\Omega$; unless otherwise specified. **Boldface** limits apply over temperature Range. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Frequency Domain Response						
SSBW	–3dB Bandwidth	$V_{OUT} = 0.5V_{PP}$		180		MHz
LSBW	–3dB Bandwidth	$V_{OUT} = 3.0V_{PP}$		110		MHz
SSBWG1	–3dB Bandwidth $A_V = 1$	$V_{OUT} = 0.25V_{PP}$		450		MHz
GFP	.1dB Bandwidth	$V_{OUT} = 1V_{PP}$		40		MHz
DG	Differential Gain	$R_L = 150\Omega$, 4.43MHz		.01		%
DP	Differential Phase	$R_L = 150\Omega$, 4.43MHz		.06		deg
Time Domain Response						
TRL		1V Step		2.2		ns
SR	Slew Rate	2V Step ⁽²⁾		800		V/ μ s
Distortion and Noise Response						
HD2	2 nd Harmonic Distortion	$2V_{PP}$, 20MHz		–63		dBc
HD3	3 rd Harmonic Distortion	$2V_{PP}$, 20MHz		–43		dBc
	Equivalent Input Noise					
VN	Voltage Noise	>1MHz		3.7		nV/ $\sqrt{\text{Hz}}$
CN	Current Noise	>1MHz		1.1		pA/ $\sqrt{\text{Hz}}$
Static, DC Performance						
V_{IO}	Input Offset Voltage			0.8	± 2.5 ± 3.5	mV
I_{BN}	Input Bias Current			–1	± 3 ± 6	μ A
I_{BI}	Input Offset Current			0	± 1.5 ± 3	μ A
PSRR	Power Supply Rejection Ratio	DC, .5V Step	67	73		dB
CMRR	Common Mode Rejection Ratio	DC, 1V Step	67	75		dB
I_{CC}	Supply Current	$R_L = \infty$		3.6	5 6	mA
Miscellaneous Performance						
R_{OUT}	Input Resistance	Close Loop		.05		Ω
V_O	Output Voltage Range	$R_L = \infty$	± 2.1	± 2.3		V
V_{OL}		$R_L = 100\Omega$	± 1.9	± 2.0		V
CMIR	Input Voltage Range	Common Mode		± 1.3		V
I_O	Linear Output Current	V_{OUT}	± 30	± 45		mA

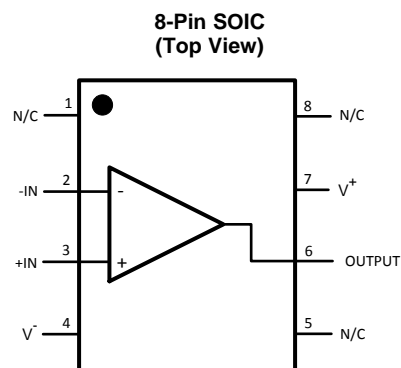
- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where $T_J > T_A$. See Applications Section for information on temperature derating of this device. Min/Max ratings are based on product characterization and simulation. Individual parameters are tested as noted.

- (2) Slew rate is Average of Rising and Falling 40-60% slew rates.

CONNECTION DIAGRAM



See Package Number D0008A



See Package Number DBV0005A

Typical Performance Characteristics

Small Signal Non-Inverting Frequency Response

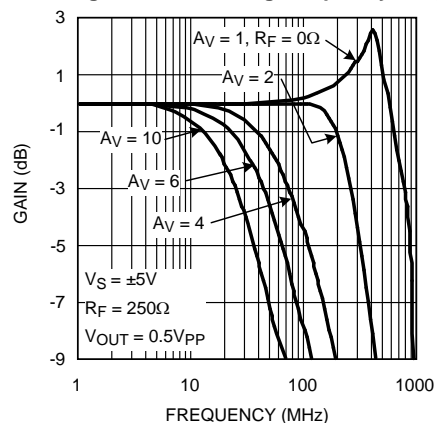


Figure 2.

Large Signal Non-Inverting Frequency Response

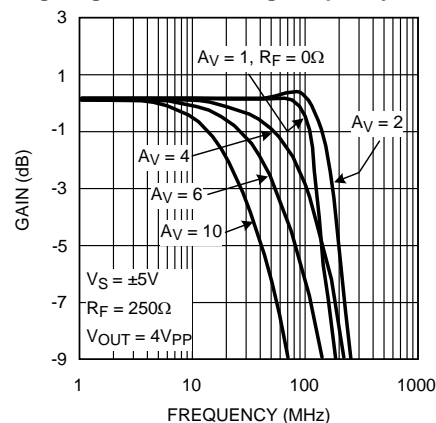


Figure 3.

Small Signal Inverting Frequency Response

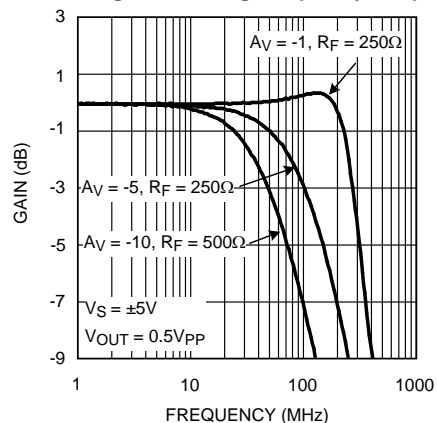


Figure 4.

Large Signal Inverting Frequency Response

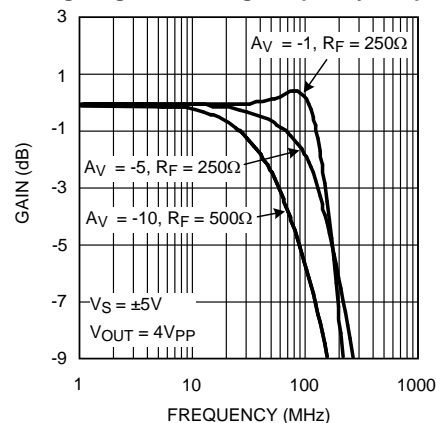


Figure 5.

Frequency Response vs. $V_{OUT} A_V = 2$

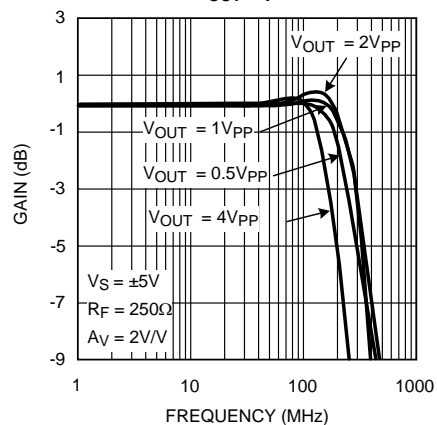


Figure 6.

Frequency Response vs. $V_{OUT} A_V = 2$

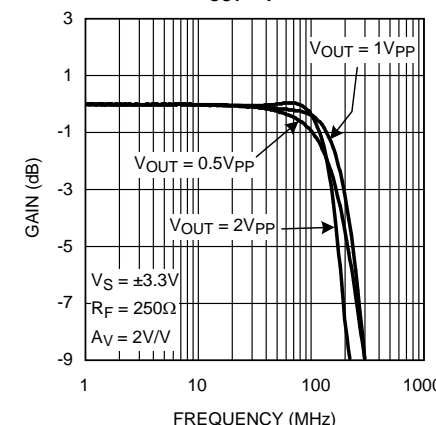


Figure 7.

Typical Performance Characteristics (continued)

Frequency Response

vs.
 $V_{OUT} A_V = 1$

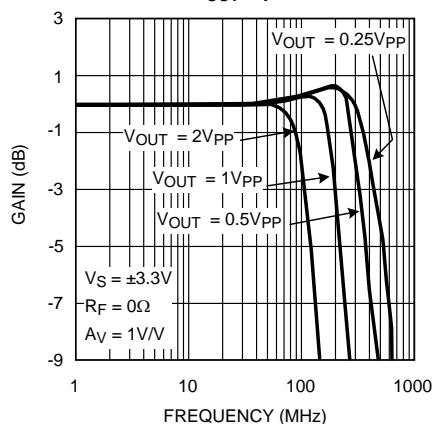


Figure 8.

Frequency Response

vs.
 $V_{OUT} A_V = -1$

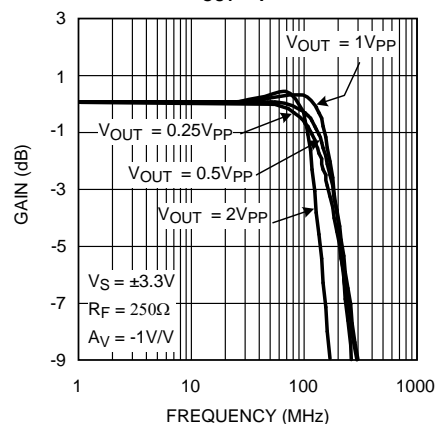


Figure 9.

Frequency Response

vs.
 $V_{OUT} A_V = -1$

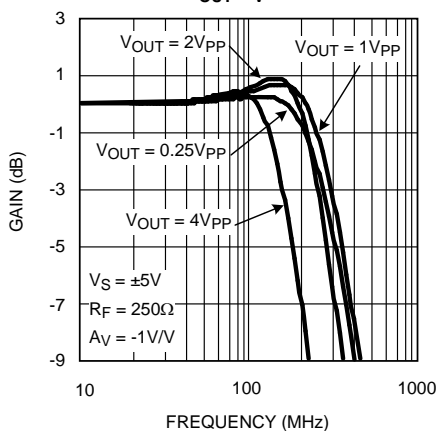


Figure 10.

Frequency Response

vs.
Cap Load

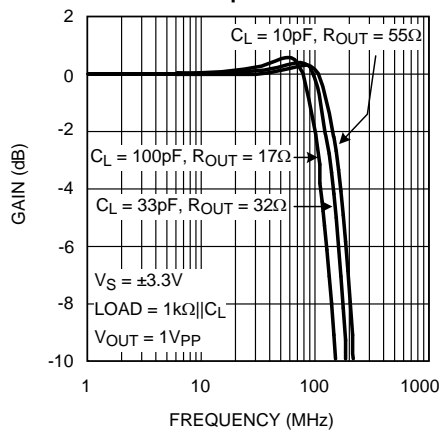


Figure 11.

Frequency Response

vs.
Cap Load

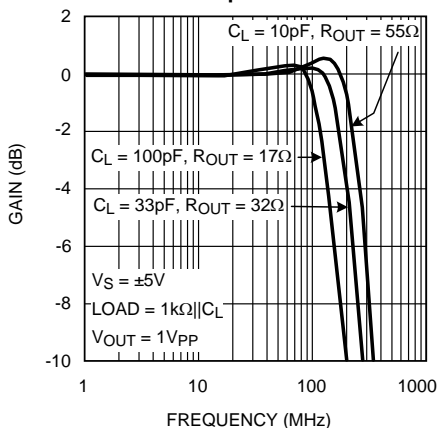


Figure 12.

Suggested R_OUT

vs.
Cap Load

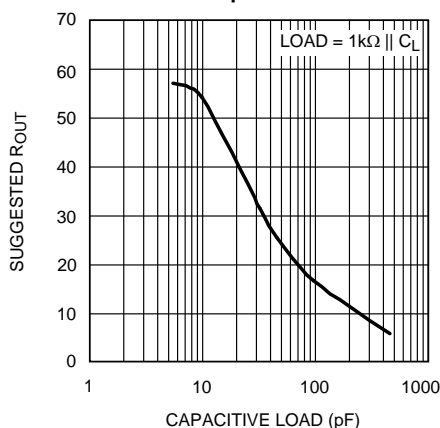


Figure 13.

Typical Performance Characteristics (continued)

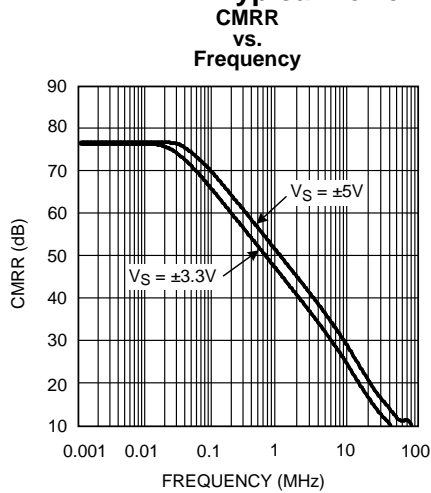


Figure 14.

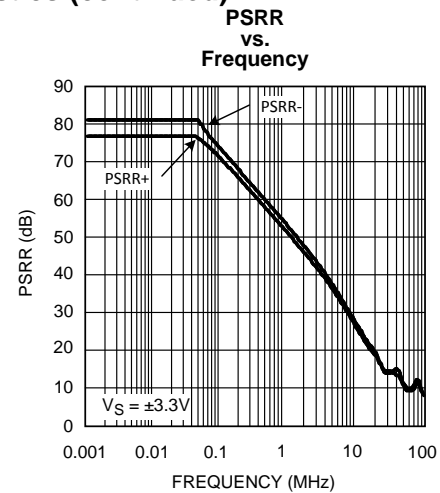


Figure 15.

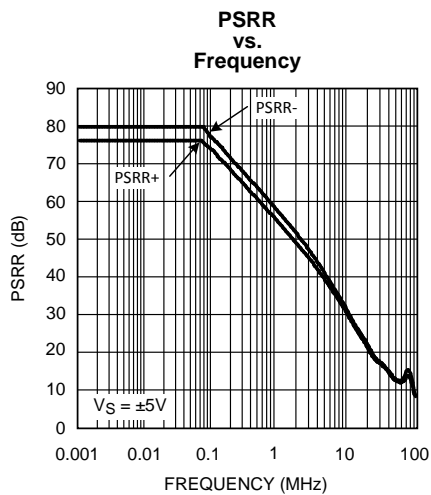


Figure 16.

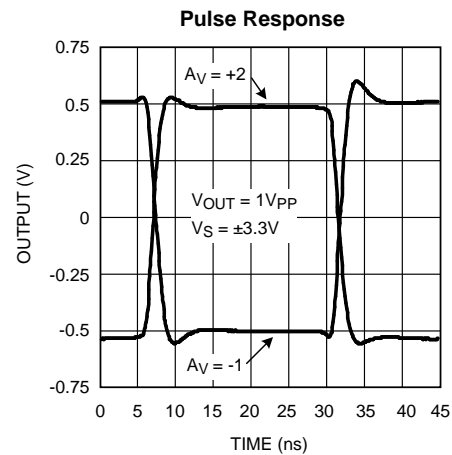


Figure 17.

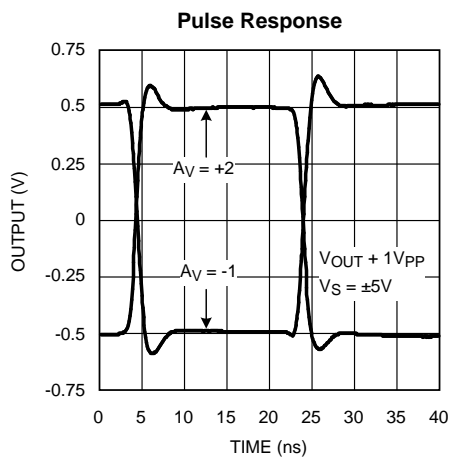


Figure 18.

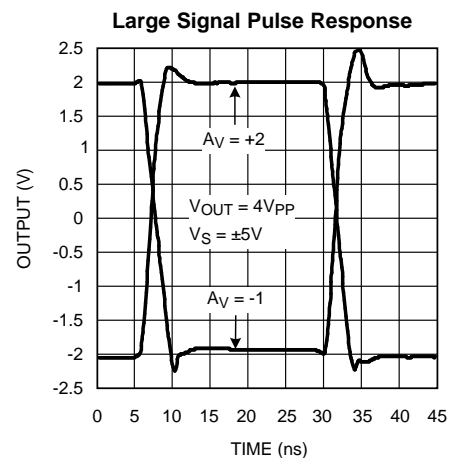


Figure 19.

Typical Performance Characteristics (continued)

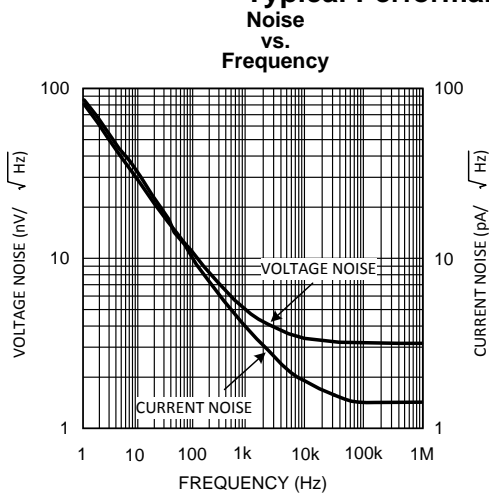


Figure 20.

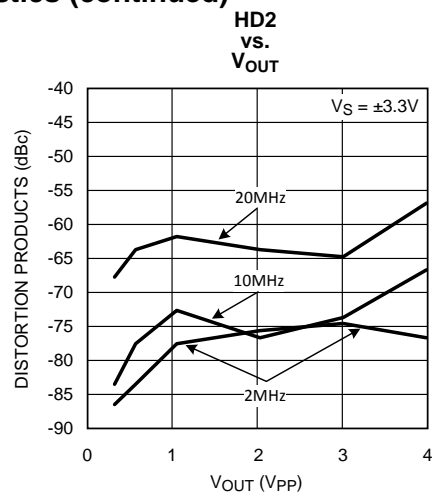


Figure 21.

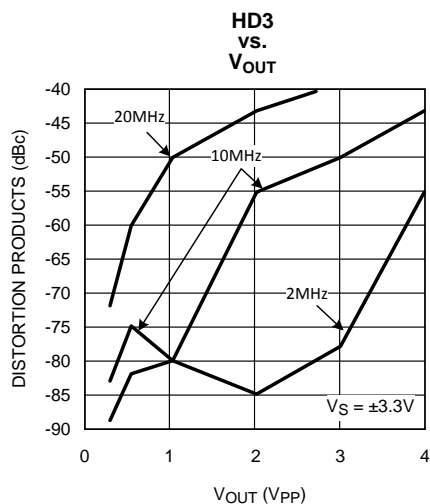


Figure 22.

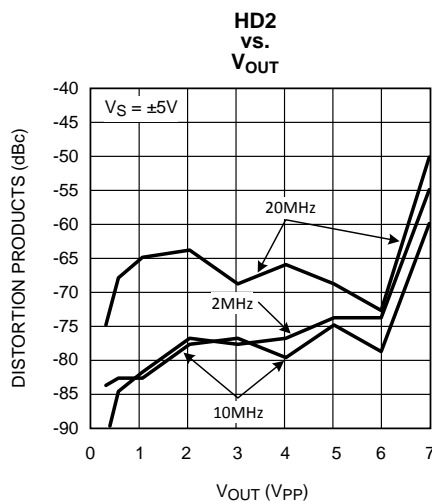


Figure 23.

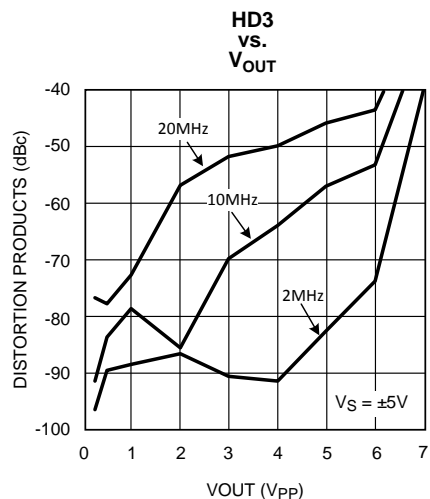


Figure 24.

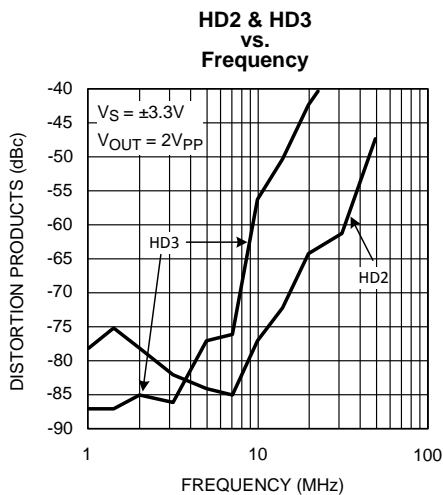


Figure 25.

Typical Performance Characteristics (continued)

HD2 & HD3
vs.
Frequency

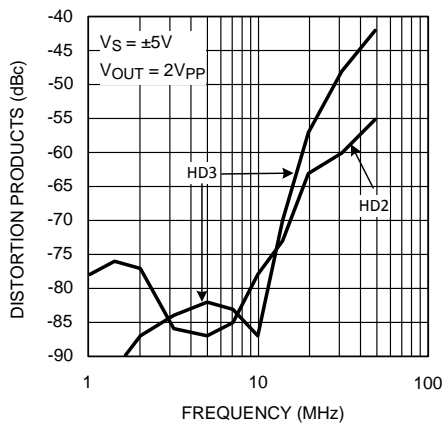


Figure 26.

Differential Gain & Phase

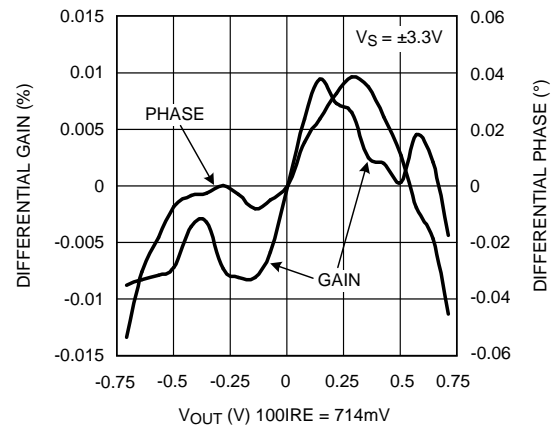


Figure 27.

Differential Gain & Phase

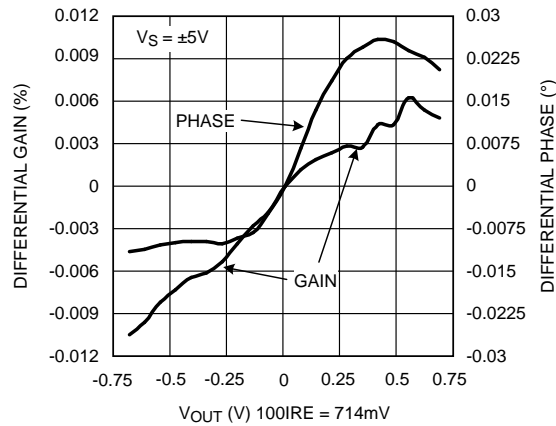


Figure 28.

Open Loop Gain & Phase

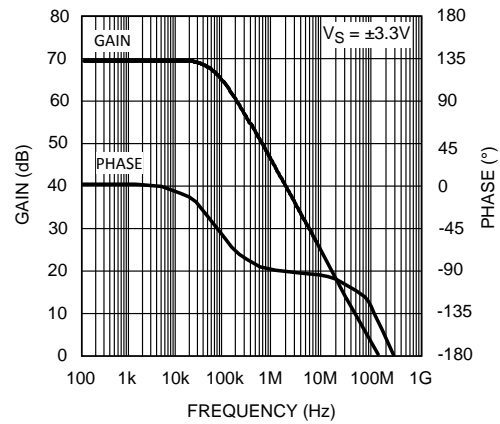


Figure 29.

Open Loop Gain & Phase

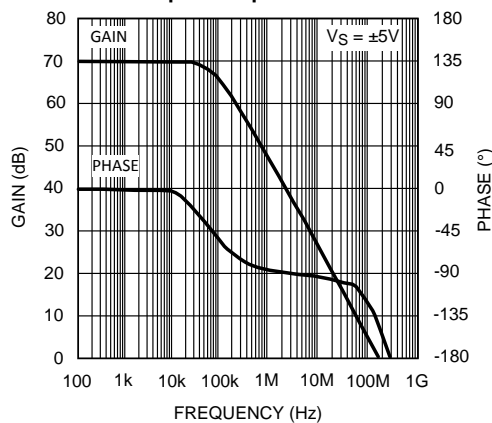


Figure 30.

Closed Loop Output Resistance

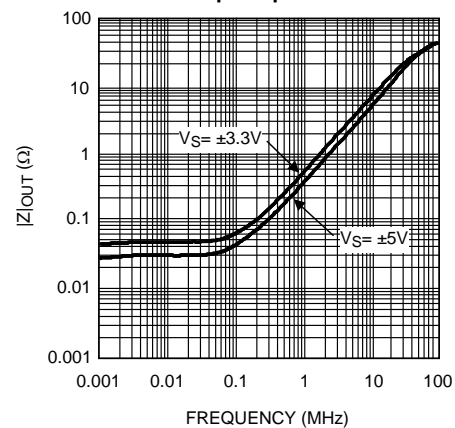


Figure 31.

APPLICATION INFORMATION

GENERAL DESIGN EQUATION

The LMH6609 is a unity gain stable voltage feedback amplifier. The matched input bias currents track well over temperature. This allows the DC offset to be minimized by matching the impedance seen by both inputs.

GAIN

The non-inverting and inverting gain equations for the LMH6609 are as follows:

$$\text{NON-INVERTING GAIN : } 1 + \frac{R_F}{R_G}$$

$$\text{INVERTING GAIN : } - \frac{R_F}{R_G}$$

(1)

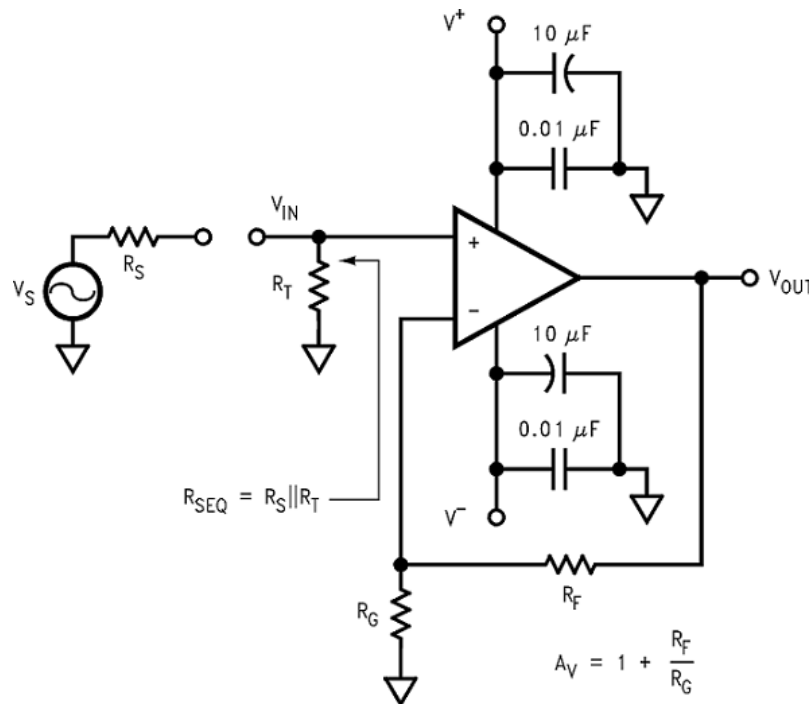


Figure 32. Typical Non-Inverting Application

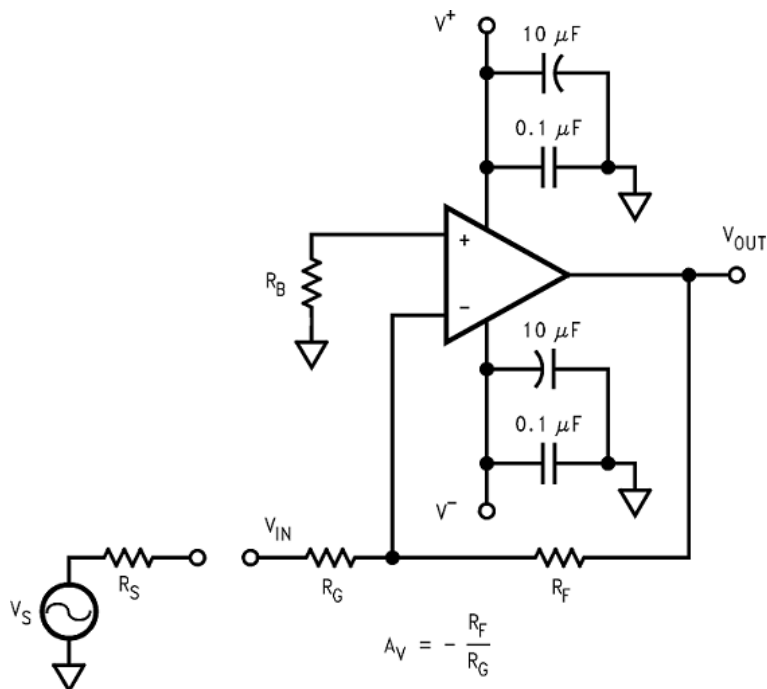


Figure 33. Typical Inverting Application

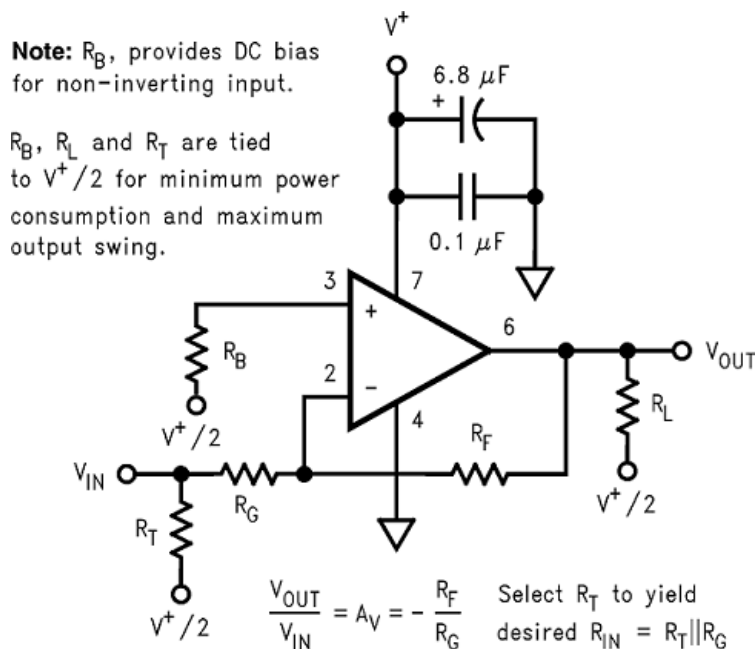


Figure 34. Single Supply Inverting

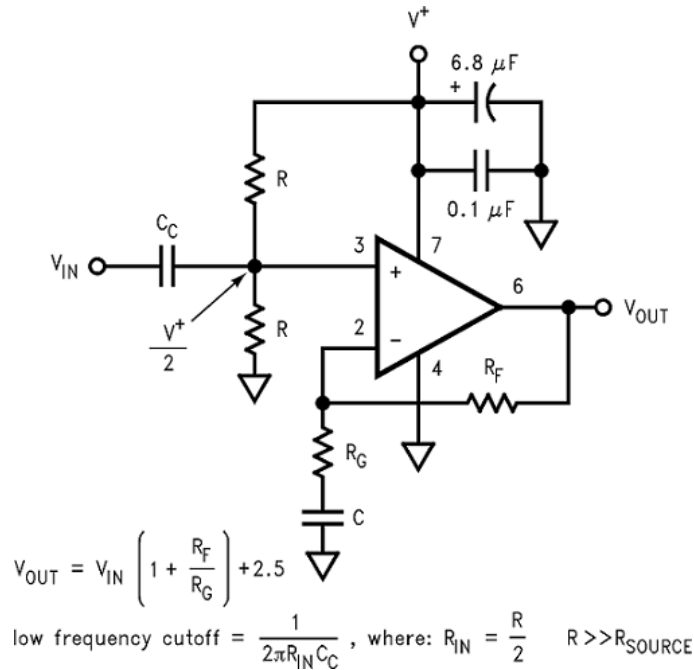


Figure 35. AC Coupled Non-Inverting

GAIN BANDWIDTH PRODUCT

The LMH6609 is a voltage feedback amplifier, whose closed-loop bandwidth is approximately equal to the gain-bandwidth product (GBP) divided by the gain (A_V). For gains greater than 5, A_V sets the closed-loop bandwidth of the LMH6609.

$$\text{CLOSED LOOP BANDWIDTH} = \frac{\text{GBP}}{A_V}$$

$$A_V = \frac{(R_F + R_G)}{R_G}$$

$$\text{GBP} = 240\text{MHz} \quad (2)$$

For Gains less than 5, refer to the frequency response plots to determine maximum bandwidth. For large signal bandwidth the slew rate is a more accurate predictor of bandwidth.

$$f_{MAX} = \frac{S_R}{2\pi V_P} \quad (3)$$

Where f_{MAX} = bandwidth, S_R = Slew rate and V_P = peak amplitude.

OUTPUT DRIVE AND SETTLING TIME PERFORMANCE

The LMH6609 has large output current capability. The 100mA of output current makes the LMH6609 an excellent choice for applications such as:

- Video Line Drivers
- Distribution Amplifiers

When driving a capacitive load or coaxial cable, include a series resistance R_{OUT} to back match or improve settling time. Refer to the Driving Capacitive Loads section for guidance on selecting an output resistor for driving capacitive loads.

EVALUATION BOARDS

TI offers the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization. Many of the data sheet plots were measured with these boards.

Device	Package	Board Part #
LMH6609MA	SOIC	LMH730227
LMH6609MF	SOT-23	LMH730216

CIRCUIT LAYOUT CONSIDERATION

A proper printed circuit layout is essential for achieving high frequency performance. TI provides evaluation boards for the LMH6609 as shown above. These boards were laid out for optimum, high-speed performance. The ground plane was removed near the input and output pins to reduce parasitic capacitance. Also, all trace lengths were minimized to reduce series inductances.

Supply bypassing is required for the amplifiers performance. The bypass capacitors provide a low impedance return current path at the supply pins. They also provide high frequency filtering on the power supply traces. 10 μ F tantalum and .01 μ F capacitors are recommended on both supplies (from supply to ground). In addition, a 0.1 μ F ceramic capacitor can be added from V^+ to V^- to aid in second harmonic suppression.

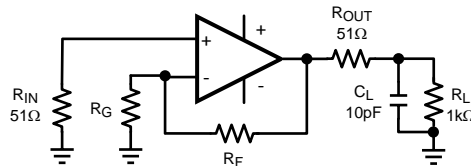


Figure 36. Driving Capacitive Loads with R_{OUT} for Improved Stability

DRIVING CAPACITIVE LOADS

Capacitive output loading applications will benefit from the use of a series output resistor R_{OUT} . Figure 36 shows the use of a series output resistor, R_{OUT} as it might be applied when driving an analog to digital converter. The charts "Suggested R_O vs. Cap Load" in the Typical Performance Section give a recommended value for mitigating capacitive loads. The values suggested in the charts are selected for .5dB or less of peaking in the frequency response. This gives a good compromise between settling time and bandwidth. For applications where maximum frequency response is needed and some peaking is tolerable, the value of R_O can be reduced slightly from the recommended values. There will be amplitude lost in the series resistor unless the gain is adjusted to compensate; this effect is most noticeable with heavy resistive loads.

COMPONENT SELECTION AND FEEDBACK RESISTOR

Surface mount components are highly recommended for the LMH6609. Leaded components will introduce unpredictable parasitic loading that will interfere with proper device operation. Do not use wire wound resistors.

The LMH6609 operates best with a feedback resistor of approximately 250Ω for all gains of +2 and greater and for –1 and less. With lower gains in particular, large value feedback resistors will exaggerate the effects of parasitic capacitances and may lead to ringing on the pulse response and frequency response peaking. Large value resistors also add undesirable thermal noise. Feedback resistors that are much below 100Ω will load the output stage, which will reduce voltage output swing, increase device power dissipation, increase distortion and reduce current available for driving the load.

In the buffer configuration the output should be shorted directly to the inverting input. This feedback does not load the output stage because the inverting input is a high impedance point and there is no gain set resistor to ground.

OPTIMIZING DC ACCURACY

The LMH6609 offers excellent DC accuracy. The well-matched inputs of this amplifier allows even better performance if care is taken to balance the impedances seen by the two inputs. The parallel combination of the gain setting R_G and feedback R_F resistors should be equal to R_{SEQ} , the resistance of the source driving the op amp in parallel with any terminating Resistor (See [Figure 32](#)). Combining this with the non inverting gain equation gives the following parameters:

$$R_F = A_{VRSEQ}$$

$$R_G = R_F / (A_V - 1)$$

For Inverting gains the bias current cancellation is accomplished by placing a resistor R_B on the non-inverting input equal in value to the resistance seen by the inverting input (See [Figure 33](#)). $R_B = R_F \parallel (R_G + R_S)$

The additional noise contribution of R_B can be minimized by the use of a shunt capacitor (not shown).

POWER DISSIPATION

The LMH6609 has the ability to drive large currents into low impedance loads. Some combinations of ambient temperature and device loading could result in device overheating. For most conditions peak power values are not as important as RMS powers. To determine the maximum allowable power dissipation for the LMH6609 use the following formula:

$$P_{MAX} = (150^\circ - T_{AMB}) / \theta_{JA} \quad (4)$$

Where T_{AMB} = Ambient temperature (°C) and θ_{JA} = Thermal resistance, from junction to ambient, for a given package (°C/W). For the SOIC package θ_{JA} is 148°C/W, for the SOT-23 it is 250°C/W. 150°C is the absolute maximum limit for the internal temperature of the device.

Either forced air cooling or a heat sink can greatly increase the power handling capability for the LMH6609.

VIDEO PERFORMANCE

The LMH6609 has been designed to provide good performance with both PAL and NTSC composite video signals. The LMH6609 is specified for PAL signals. NTSC performance is typically marginally better due to the lower frequency content of the signal. Performance degrades as the loading is increased, therefore best performance will be obtained with back-terminated loads. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage. This means that the device should be configured for a gain of 2 in order to have a net gain of 1 after the terminating resistor. (See [Figure 37](#))

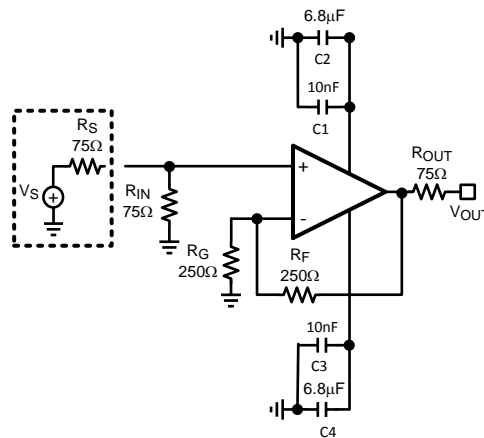


Figure 37. Typical Video Application

ESD PROTECTION

The LMH6609 is protected against electrostatic discharge (ESD) on all pins. The LMH6609 will survive 2000V Human Body model or 200V Machine model events.

Under closed loop operation the ESD diodes have no effect on circuit performance. There are occasions, however, when the ESD diodes may be evident. For instance, if the amplifier is powered down and a large input signal is applied the ESD diodes will conduct.

TRANSIMPEDANCE AMPLIFIER

The low input current noise and unity gain stability of the LMH6609 make it an excellent choice for transimpedance applications. Figure 38 illustrates a low noise transimpedance amplifier that is commonly implemented with photo diodes. R_F sets the transimpedance gain. The photo diode current multiplied by R_F determines the output voltage.

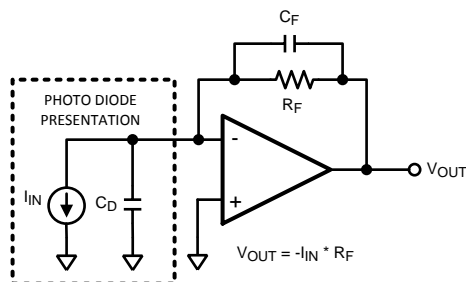


Figure 38. Transimpedance Amplifier

The capacitances are defined as:

- C_D = Equivalent Diode Capacitance
- C_F = Feedback Capacitance

The feedback capacitor is used to give optimum flatness and stability. As a starting point the feedback capacitance should be chosen as $\frac{1}{2}$ of the Diode capacitance. Lower feedback capacitors will peak frequency response.

Rectifier

The large bandwidth of the LMH6609 allows for high-speed rectification. A common rectifier topology is shown in Figure 39. R_1 and R_2 set the gain of the rectifier.

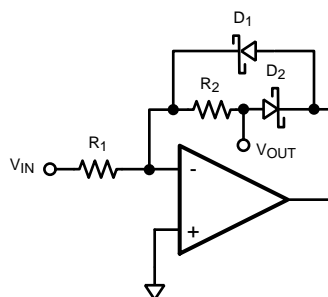


Figure 39. Rectifier Topology

REVISION HISTORY

Changes from Revision E (March 2013) to Revision F	Page
• Changed layout of National Data Sheet to TI format	17

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMH6609MA	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LMH66 09MA	Samples
LMH6609MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH66 09MA	Samples
LMH6609MAX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	LMH66 09MA	Samples
LMH6609MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH66 09MA	Samples
LMH6609MF	ACTIVE	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	A89A	Samples
LMH6609MF/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A89A	Samples
LMH6609MFX	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 85	A89A	Samples
LMH6609MFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A89A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

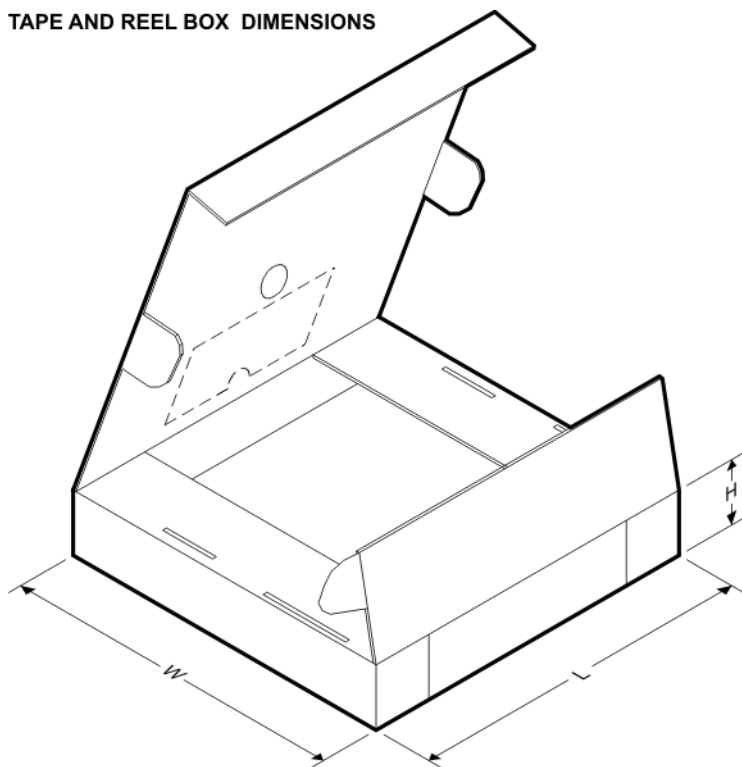
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH6609MAX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH6609MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH6609MF	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6609MF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6609MFX	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6609MFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

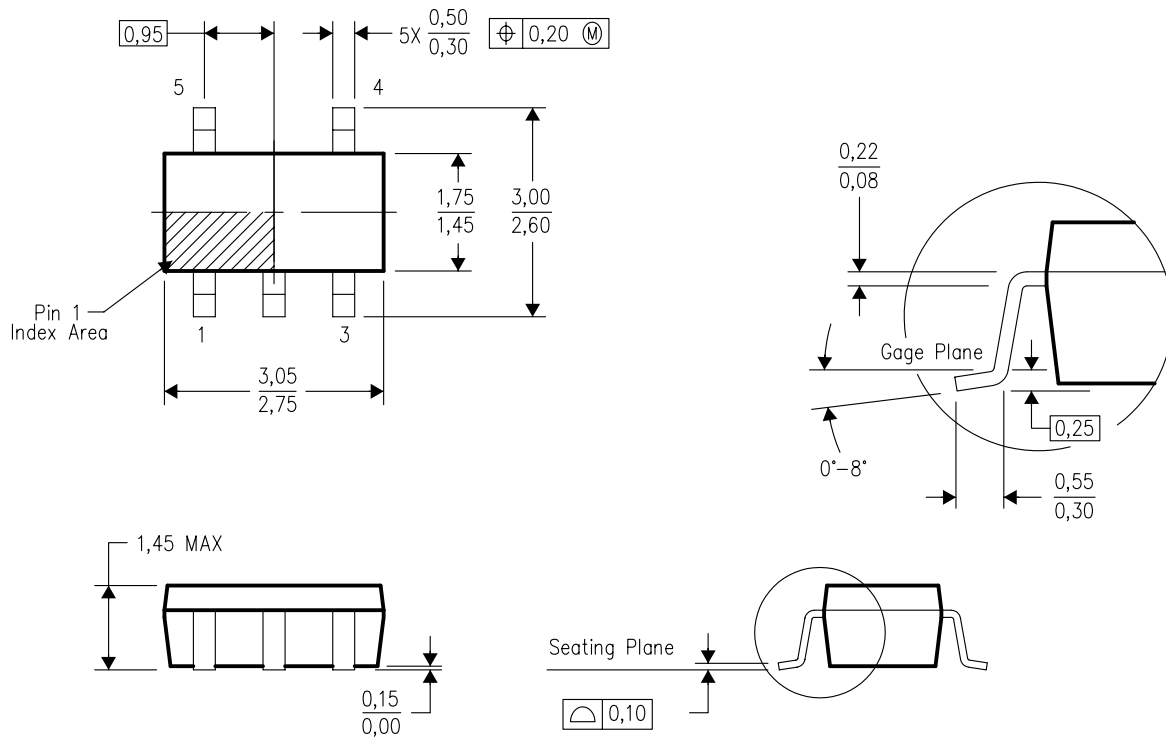


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH6609MAX	SOIC	D	8	2500	367.0	367.0	35.0
LMH6609MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMH6609MF	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMH6609MF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMH6609MFX	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMH6609MFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE

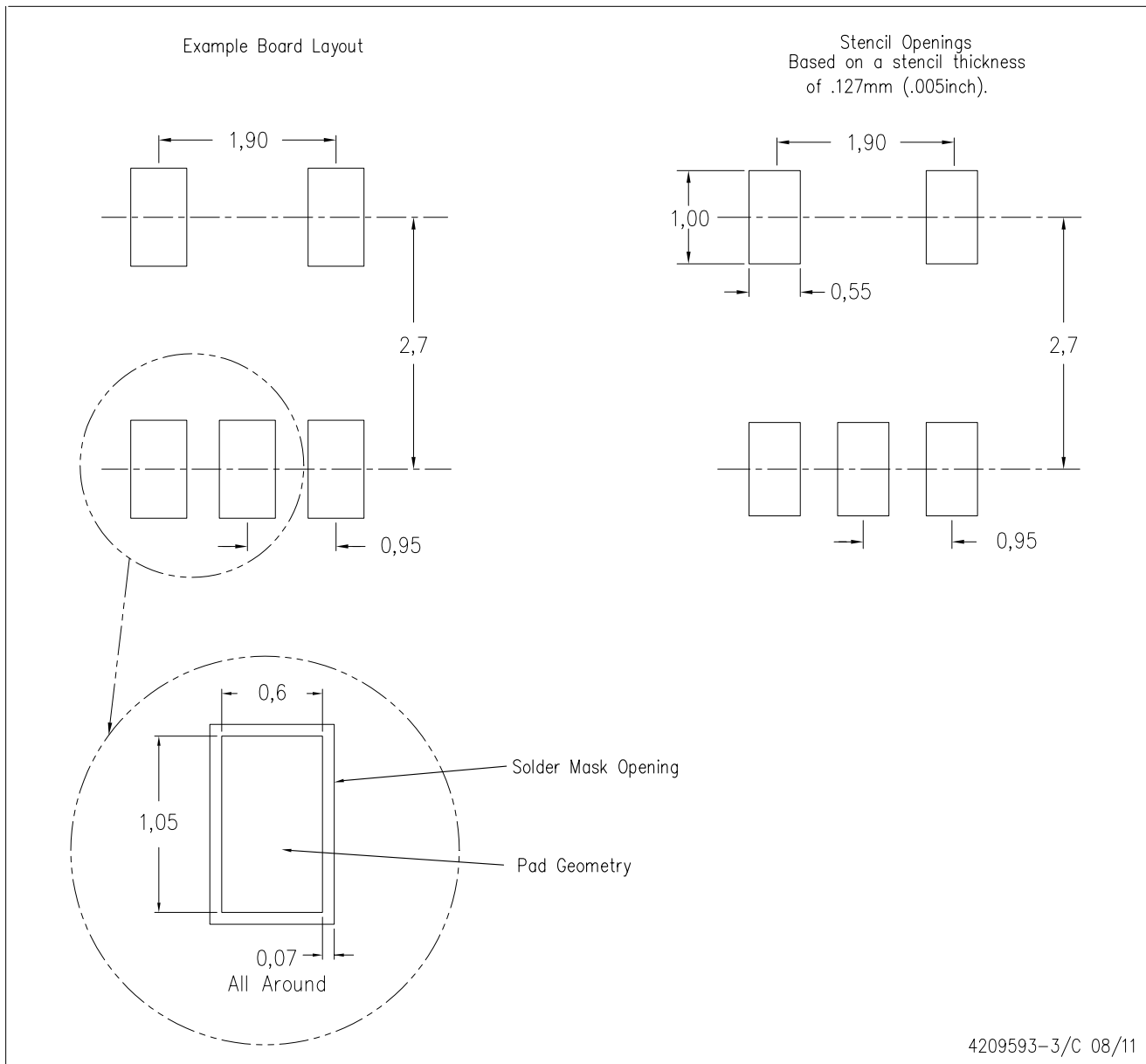


4073253-4/K 03/2006

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

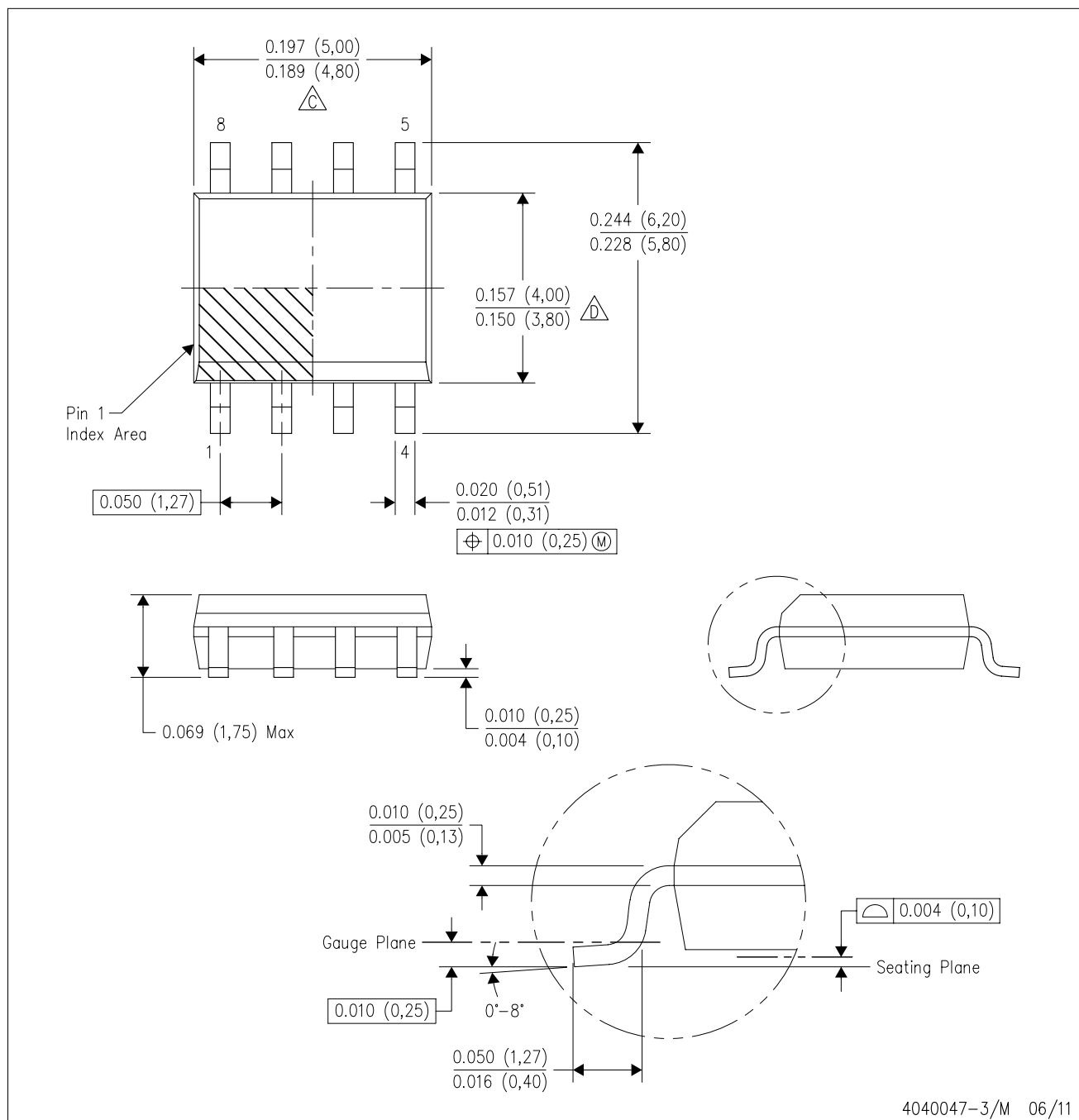
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.